Power transistor (60V, 3A)

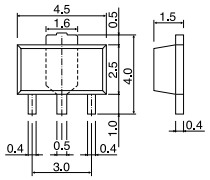
2SC5824

●Features

1) High speed switching. (Tf : Typ. : 30ns at I_C = 3A)
2) Low saturation voltage, typically (Typ. : 200mV at I_C = 2A, I_B = 200mA)
3) Strong discharge power for inductive load and capacitance load.
4) Complements the 2SA2071.

●Dimensions (Unit : mm)

MPT3



(1)Base(Gate)
(2)Collector(Drain)
(3)Emitter(Sourse)

Each lead has same dimensions

Abbreviated symbol : UP

●Applications

NPN Silicon epitaxial planar transistor

●Structure

Low frequency amplifier
High speed switching

●Packaging specifications

Type	Package	Taping
	Code	T100
	Basic ordering unit (pieces)	1000
2SC5824		○

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	60	V
Collector-emitter voltage	V_{CEO}	60	V
Emitter-base voltage	V_{EBO}	6	V
Collector current	I_C	3	A
	I_{CP}	6	A *1
Power dissipation	P_C	500	mW *2
	P_C	2.0	W *3
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	−55~+150	°C

*1 Pw=100ms
*2 Each terminal mounted on a recommended land.
*3 Mounted on a 40x40x0.7(mm) ceramic substrate

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector–base breakdown voltage	BV_{CBO}	60	–	–	V	I_C=100μA
Collector–emitter breakdown voltage	BV_{CEO}	60	–	–	V	I_C=1mA
Emitter–base breakdown voltage	BV_{EBO}	6	–	–	V	I_E=100μA
Collector cut-off current	I_{CBO}	–	–	1.0	μA	V_{CB}=40V
Emitter cut-off current	I_{EBO}	–	–	1.0	μA	V_{EB}=4V
Collector–emitter staturation voltage	$V_{CE(sat)}$	–	200	500	mV	I_C=2A, I_B=200mA *1
DC current gain	h_{FE}	120	–	390	–	V_{CE}=2V, I_C=100mA
Transition frequency	f_T	–	200	–	MHz	V_{CE}=10V, I_E= –100mA, f=10MHz *1
Collector output capacitance	C_{ob}	–	20	–	pF	V_{CB}=10V, I_E=0mA, f=1MHz
Turn-on time	t_{on}	–	50	–	ns	I_C=3A, I_{B1}=300mA I_{B2}= –300mA V_{CC}≒25V *2
Storage time	t_{stg}	–	150	–	ns	
Fall time	tf	–	30	–	ns	

*1 Non repetitive pulse
*2 See switching charactaristics measurement circuits

●h_{FE} RANK

Q	R
120-270	180-390

●Electrical characteristic curves

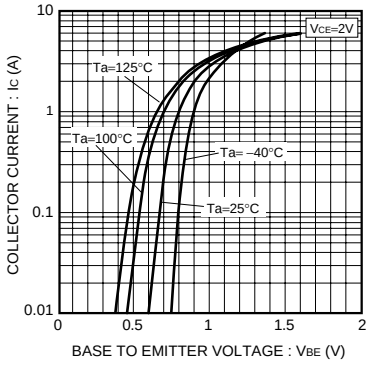


Fig.1 Ground emitter propagation characteristics

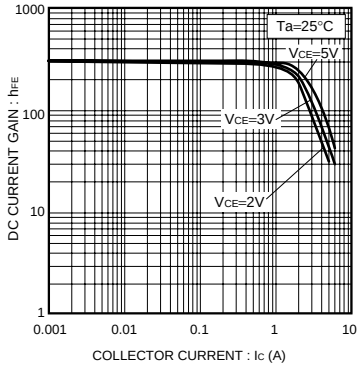


Fig.2 DC current gain vs. collector current

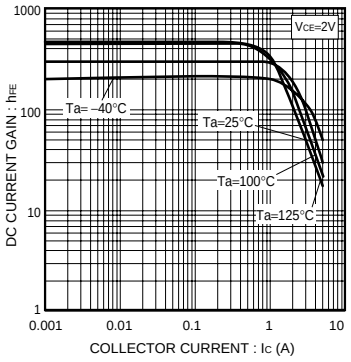


Fig.3 DC current gain vs. collector current

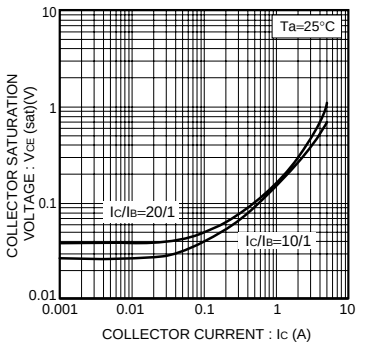


Fig.4 Collector-emitter saturation voltage vs. collector current

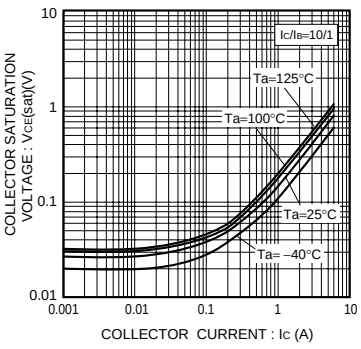


Fig.5 Collector-emitter saturation voltage vs. Collector Current

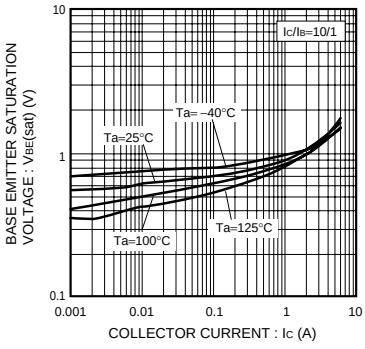


Fig.6 Base-emitter saturation voltage vs. collector current

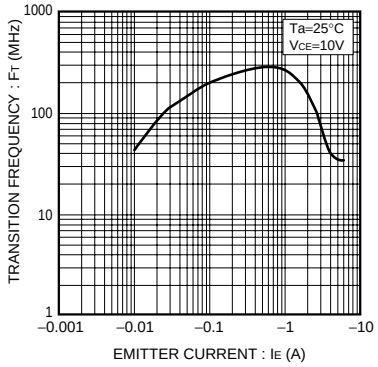


Fig.7 Transition frequency

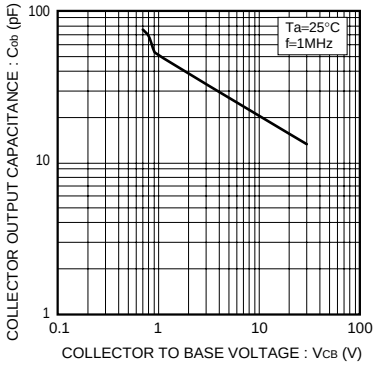


Fig.8 Collector output capacitance

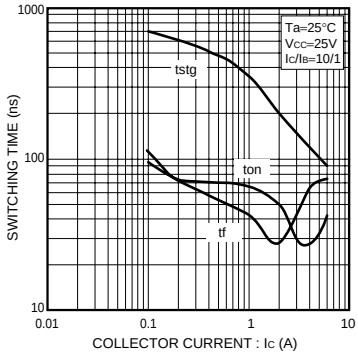


Fig.9 Switching Time

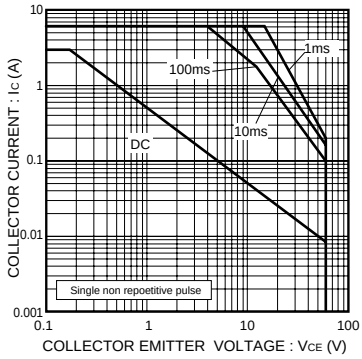
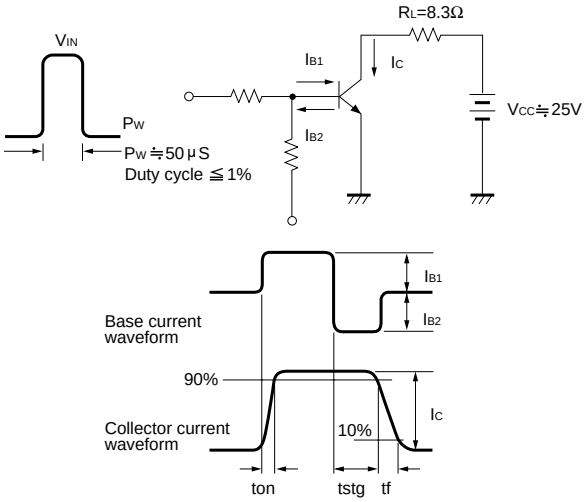


Fig.10 Safe operating area

●Switching characteristics measurement circuits



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